

Supporting Information

Thermally Evaporated Copper Iodide Hole-Transporter for Stable CdS/CdTe Thin-Film Solar Cells

Thuraisamykurukkal Thivakarasarma ^{1,2}, Adikari Arachchige Isuru Lakmal ^{3,4}, Buddhika Senarath Dassanayake ^{3,4}, Dhayalan Velauthapillai ^{2,*} and Punniamoorthy Ravirajan ^{1,*}

¹ Clean Energy Research Laboratory, Department of Physics, University of Jaffna, Jaffna 40000, Sri Lanka; tsarma1990@gmail.com

² Faculty of Engineering and Science, Western Norway University of Applied Sciences, P.O. Box 7030, 5020 Bergen, Norway

³ Postgraduate Institute of Science, University of Peradeniya, Peradeniya 20400, Sri Lanka; aaisurulakmal@gmail.com (A.A.I.L.); buddhikad@pdn.ac.lk (B.S.D.)

⁴ Department of Physics, University of Peradeniya, Peradeniya 20400, Sri Lanka

* Correspondence: pravirajan@univ.jfn.ac.lk (P.R.); dhayalan.velauthapillai@hvl.no (D.V.)

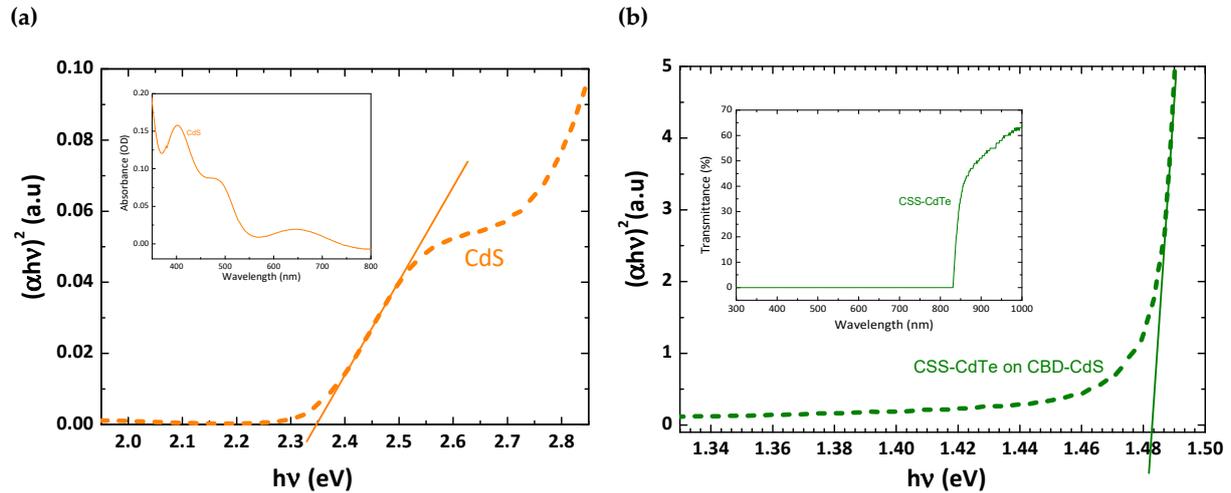


Figure S1: Optical absorption spectra of (a) Chemically deposited CdS film and (b) closed space sublimated CdTe film.

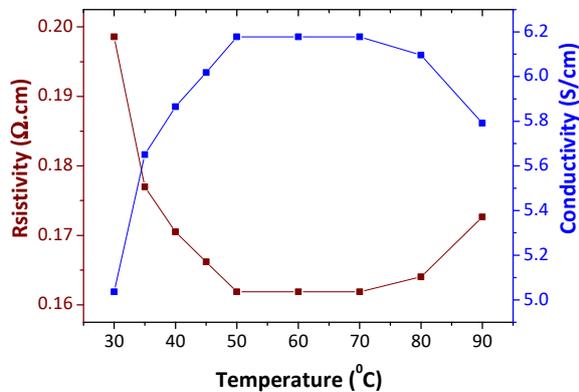


Figure S2: Temperature dependant electrical property of thermally evaporated CuI.

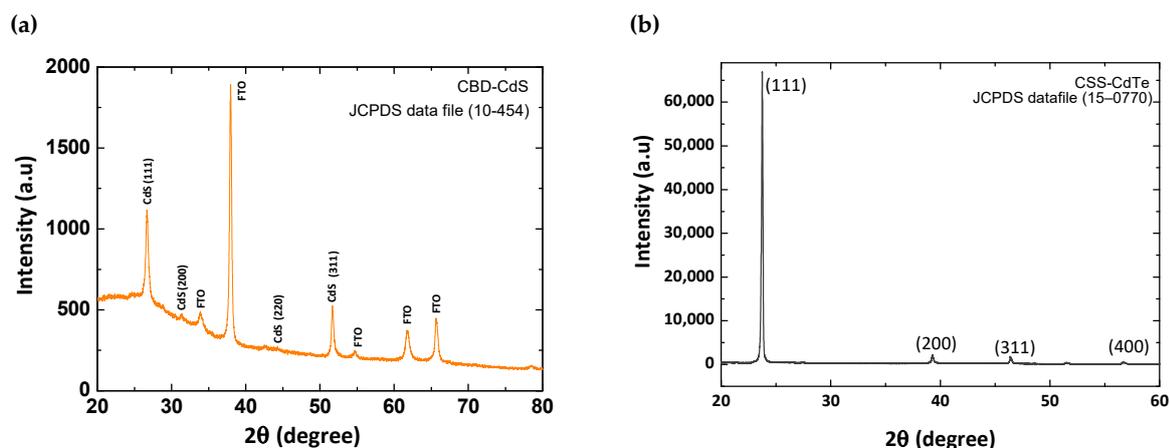


Figure S3: XRD pattern of (a) CBD-CdS and (b) CSS-CdTe.

Table S1: Average crystallite size of CBD-CdS and CSS-CdTe.

Film	Average crystallite size (nm)
CBD-CdS	18.20
CSS-CdTe	45.47

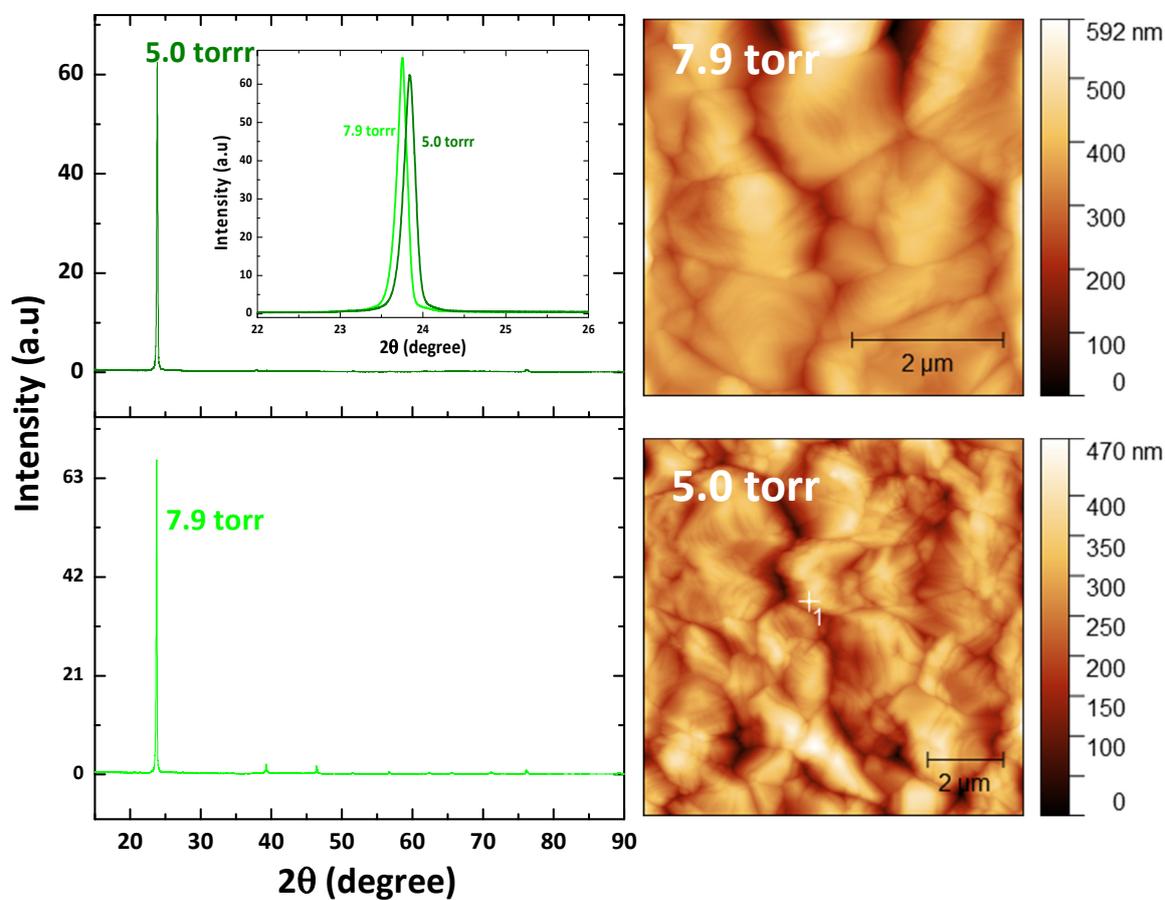


Figure S4: XRD pattern and AFM Topography images of CSS-CdTe with different fabrication parameter

Table S2: Structural parameters of CSS-CdTe with different fabrication parameter.

Vacuum Pressure	Lattice Parameter (Å)	Crystallite size D (nm)	Micro strain ϵ (10^{-3})
7.9 torr	6.49	50.62	3.33
5.0 torr	6.46	45.47	3.69

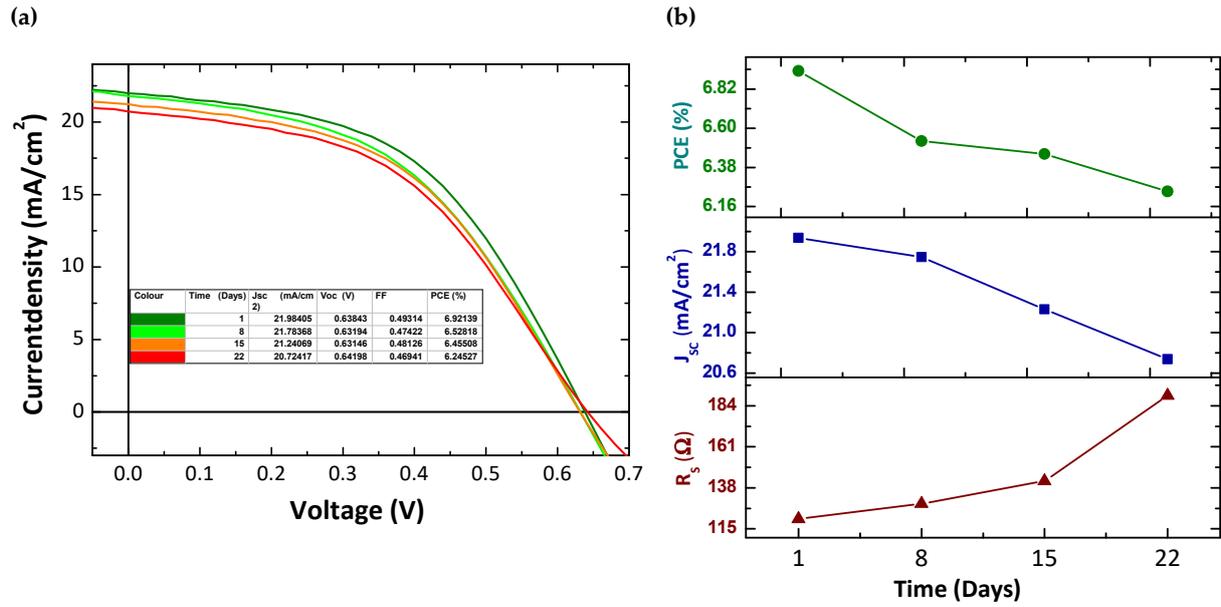


Figure S5: (a) J-V characteristic and (b) Variation of photovoltaic parameters of CdS/CdTe/CuI/Au solar cells with time.